FEATURES

- Temperature Compensated Internal Schottky Diode RF Detector
- Wide Input Power Range: –34dBm to 14dBm
- Ultra Wide Input Frequency Range: 100kHz to 1000MHz
- Buffered Output
- Wide VCC Range of 2.7V to 6V
- Low Operating Current: 550μA
- Low Shutdown Current: <2μA
- Low Profile (1mm) ThinSOT™ Package

APPLICATIONS

- Wireless Transceivers
- Wireless and Cable Infrastructure
- RF Power Alarm
- Envelope Detector

DESCRIPTION

The LTC®5507 is an RF power detector for applications operating from 100kHz to 1000MHz. The input frequency range is determined by an external capacitor. A temperature-compensated Schottky diode peak detector and buffer amplifier are combined in a small 6-pin ThinSOT package.

The RF input voltage is peak detected using an on-chip Schottky diode and external capacitor. The detected voltage is buffered and supplied to the VOUT pin. A power saving shutdown mode reduces supply current to less than 2μA.

TYPICAL APPLICATION

![Diagram](image)

Figure 1. 100kHz to 1000MHz RF Power Detector

Typical Detector Characteristics at 100kHz, 100MHz and 1000MHz

VCC = 2.7V TO 6V
**ABSOLUTE MAXIMUM RATINGS**  
(Not e 1)

- $V_{CC}$, $V_{OUT}$ to GND .................................. $-0.3V$ to $6.5V$  
- $RF\text{IN}$ Voltage to GND .................. ($V_{CC} \pm 1.8V$) to $7V$  
- $SHDN$ Voltage to GND ................. $-0.3V$ to ($V_{CC} + 0.3V$)  
- $PCAP$ Voltage to GND ................... ($V_{CC} - 1.8V$) to $7V$  
- $I_{VOUT}$ .................................. 5mA  

Operating Temperature Range (Note 2) . . $-40\degree C$ to $85\degree C$  
Maximum Junction Temperature ....................... $125\degree C$  
Storage Temperature Range ........... $-65\degree C$ to $150\degree C$  
Lead Temperature (Soldering, 10 sec) .............. $300\degree C$

**ELECTRICAL CHARACTERISTICS** The • denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25\degree C$. $V_{CC} = 3.6V$, $RF$ Input Signal is Off, unless otherwise noted.

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{CC}$ Operating Voltage</td>
<td>•</td>
<td>2.7</td>
<td>6</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>$I_{VCC}$ Shutdown Current</td>
<td>$SHDN = 0V$</td>
<td>•</td>
<td>2</td>
<td>$\mu A$</td>
<td></td>
</tr>
<tr>
<td>$I_{VCC}$ Operating Current</td>
<td>$SHDN = V_{CC}$, $I_{VOUT} = 0mA$</td>
<td>•</td>
<td>0.55</td>
<td>0.85</td>
<td>mA</td>
</tr>
<tr>
<td>$V_{OUT}$ VOL (No RF Input)</td>
<td>$R_{LOAD} = 2k$, $SHDN = V_{CC}$, Enabled $SHDN = 0V$, Disabled</td>
<td>130</td>
<td>250</td>
<td>370</td>
<td>mV</td>
</tr>
<tr>
<td>$V_{OUT}$ Output Current</td>
<td>$V_{OUT} = 1.75V$, $V_{CC} = 2.7V$ to $6V$, $\Delta V_{OUT} = 10mV$</td>
<td>•</td>
<td>1</td>
<td>2</td>
<td>mA</td>
</tr>
<tr>
<td>$V_{OUT}$ Enable Time</td>
<td>$SHDN = V_{CC}$, $C_{LOAD} = 33pF$, $R_{LOAD} = 2k$</td>
<td>•</td>
<td>7</td>
<td>20</td>
<td>$\mu s$</td>
</tr>
<tr>
<td>$V_{OUT}$ Load Capacitance</td>
<td>(Note 4)</td>
<td>•</td>
<td>33</td>
<td>pF</td>
<td></td>
</tr>
<tr>
<td>$V_{OUT}$ Noise</td>
<td>$V_{CC} = 3V$, Noise BW = 1.5MHz, 50$\Omega$ RF Input Termination</td>
<td>2</td>
<td>mVP-P</td>
<td></td>
<td></td>
</tr>
<tr>
<td>$SHDN$ Voltage, Chip Disabled</td>
<td>$V_{CC} = 2.7V$ to $6V$</td>
<td>•</td>
<td>0.35</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>$SHDN$ Voltage, Chip Enabled</td>
<td>$V_{CC} = 2.7V$ to $6V$</td>
<td>•</td>
<td>1.4</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>$SHDN$ Input Current</td>
<td>$SHDN = 3.6V$</td>
<td>•</td>
<td>24</td>
<td>40</td>
<td>$\mu A$</td>
</tr>
<tr>
<td>$RF\text{IN}$ Input Frequency Range</td>
<td></td>
<td></td>
<td>0.1–1000</td>
<td>MHz</td>
<td></td>
</tr>
<tr>
<td>Max $RF\text{IN}$ Input Power</td>
<td>(Note 3)</td>
<td></td>
<td>14</td>
<td>dBm</td>
<td></td>
</tr>
<tr>
<td>$RF\text{IN}$ AC Input Resistance</td>
<td>$F = 10MHz$, $RF$ Input = $-10dBm$</td>
<td></td>
<td>130</td>
<td>$\Omega$</td>
<td></td>
</tr>
<tr>
<td>$F = 1000MHz$, $RF$ Input = $-10dBm$</td>
<td></td>
<td></td>
<td>95</td>
<td>$\Omega$</td>
<td></td>
</tr>
<tr>
<td>$RF\text{IN}$ Input Shunt Capacitance</td>
<td></td>
<td></td>
<td>1.7</td>
<td>pF</td>
<td></td>
</tr>
</tbody>
</table>

**Note 1**: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.  
**Note 2**: Specifications over the $-40\degree C$ to $85\degree C$ operating temperature range are assured by design, characterization and correlation with statistical process controls.  
**Note 3**: RF performance is tested at: $80MHz$, $-4dBm$  
**Note 4**: Guaranteed by design.
TYPICAL PERFORMANCE CHARACTERISTICS

LTC5507 Typical Detector Characteristics, 100kHz, $V_{CC} = 2.7V$ TO 6V

LTC5507 Typical Detector Characteristics, 100 MHz, $V_{CC} = 2.7V$ TO 6V

Positive $V_{OUT}$ Slew Rate vs $C_2$ Capacitance

Negative $V_{OUT}$ Slew Rate vs $C_2$ Capacitance

$V_{OUT}$ BW vs $C_2$ Capacitance

$V_{OUT}$ BW vs $C_2$ Capacitance
**PIN FUNCTIONS**

**SHDN (Pin 1):** Shutdown Input. A logic low or no-connect on the SHDN pin places the part in shutdown mode. A logic high enables the part. SHDN has an internal 150k pull down resistor to ensure that the part is in shutdown when the enable driver is in a tri-state condition.

**GND (Pin 2):** System Ground.

**VOUT (Pin 3):** Buffered and Level Shifted Detector Output Voltage.

**VCC (Pin 4):** Power Supply Voltage, 2.7V to 6V. VCC should be bypassed with 0.1\(\mu\)F and 100pF ceramic capacitors.

**PCAP (Pin 5):** Peak Detector Hold Capacitor. Capacitor value is dependent on RF frequency. Capacitor must be connected between PCAP and VCC.

**RFIN (Pin 6):** RF Input Voltage. Referenced to VCC. A coupling capacitor must be used to connect to the RF signal source. This pin has an internal 250\(\Omega\) termination and an internal Schottky diode detector.

**BLOCK DIAGRAM**

![Block Diagram](image)

**C1 = C2**

\[ C2 (\mu F) \geq \frac{1}{30f} \], \( f = \text{LOWEST RF INPUT FREQUENCY (MHz)} \)

**Figure 2.**
APPLICATIONS INFORMATION

Operation
The LTC5507 integrates several functions to provide RF power detection over frequencies up to 1000MHz. These functions include an internally compensated buffer amplifier, an RF Schottky diode peak detector and level shift amplifier to convert the RF signal to DC, a delay circuit to avoid voltage transients at VOUT when coming out of shutdown, and a gain compression circuit to extend the detector dynamic range.

Buffer Amplifier
The buffer amplifier has a gain of two and is capable of driving a 2mA load. The buffer amplifier typically has an output voltage range of 0.25V to VCC – 0.1V.

RF Detector
The internal RF Schottky diode peak detector and level shift amplifier converts the RF input signal to a low frequency signal. The frequency range of the RF pin is typically up to 1000MHz. The detector demonstrates excellent operation over a wide range of input power. The Schottky detector is biased at about 70μA. The hold capacitor is external.

Gain Compression
The gain compression circuit changes the feedback ratio as the RF peak-detected input voltage increases above 60mV. Below 60mV, the DC voltage gain from the peak detector to the buffer output is 4. Above 140mV, the DC voltage gain is reduced to 0.75. The compression expands the low power detector range due to higher gain.

Modes of Operation

<table>
<thead>
<tr>
<th>MODE</th>
<th>SHDN</th>
<th>OPERATION</th>
</tr>
</thead>
<tbody>
<tr>
<td>Shutdown</td>
<td>Low</td>
<td>Disabled</td>
</tr>
<tr>
<td>Enable</td>
<td>High</td>
<td>Power Detect</td>
</tr>
</tbody>
</table>

Applications
The LTC5507 can be used as a self-standalone signal strength measuring receiver for a wide range of input signals from –34dBm to 14dBm for frequencies up to 1000MHz.

The LTC5507 can be used as a demodulator for AM and ASK modulated signals with data rates up to 1.5MHz. Depending on specific application needs, the RSSI output can be split into two branches, providing AC-coupled data (or audio) output and DC-coupled, RSSI output for signal strength measurements and AGC.

C1, C2 Capacitor Selection (Refer to Figure 3)
C1 couples the RF input signal to the detector input RFIN which is referenced to VCC. C2 is the peak detector capacitor connected between PCAP and VCC. The value of C2 will affect the slew rate and bandwidth. Typically C1 can equal C2. Ceramic capacitors are recommended for C1 and C2. The values for C1 and C2 are dependent on the operating RF frequency. The capacitive reactance should be less than 5Ω to minimize ripple on C2.

\[ C2(\mu F) \geq 1/(30 \cdot f) \text{ where } f \text{ is the lowest RF input frequency (MHz)} \]

\[ C1 = C2 \]

In general, select C1 and C2 large enough to pass the lowest expected RF signal frequency, as described by the above formulas. But optimize C1 and C2, subject to this constraint, to improve output slew rate and bandwidth, and to enable good AC performance for the highest expected RF signal frequency.
* OPTIONAL COMPONENTS
R2 AND C5 FORM AN OPTIONAL OUTPUT LOWPASS FILTER.
R3 IS USED FOR DEMO PURPOSES ONLY, AND IS NOT USED IN ACTUAL PRODUCT IMPLEMENTATION.
R4 CAN BE USED FOR INPUT POWER LIMITING OR BROADBAND IMPEDANCE MATCHING.
C3 AND C4 ARE OPTIONAL POWER SUPPLY FILTERS.

Figure 3. Evaluation Demo Board Schematic
PACKAGE DESCRIPTION

S6 Package
6-Lead Plastic TSOT-23
(Reference LTC DWG # 05-08-1636)

RECOMMENDED SOLDER PAD LAYOUT
PER IPC CALCULATOR

NOTE:
1. DIMENSIONS ARE IN MILLIMETERS
2. DRAWING NOT TO SCALE
3. DIMENSIONS ARE INCLUSIVE OF PLATING
4. DIMENSIONS ARE EXCLUSIVE OF MOLD FLASH AND METAL BURR
5. MOLD FLASH SHALL NOT EXCEED 0.254mm
6. JEDEC PACKAGE REFERENCE IS MO-193

Information furnished by Linear Technology Corporation is believed to be accurate and reliable. However, no responsibility is assumed for its use. Linear Technology Corporation makes no representation that the interconnection of its circuits as described herein will not infringe on existing patent rights.
## RELATED PARTS

<table>
<thead>
<tr>
<th>PART NUMBER</th>
<th>DESCRIPTION</th>
<th>COMMENTS</th>
</tr>
</thead>
<tbody>
<tr>
<td><strong>RF Power Controllers</strong></td>
<td></td>
<td></td>
</tr>
<tr>
<td>LTC1757A</td>
<td>RF Power Controller</td>
<td>Multiband GSM/DCS/GPRS Mobile Phones</td>
</tr>
<tr>
<td>LTC1758</td>
<td>RF Power Controller</td>
<td>Multiband GSM/DCS/GPRS Mobile Phones</td>
</tr>
<tr>
<td>LTC1957</td>
<td>RF Power Controller</td>
<td>Multiband GSM/DCS/GPRS Mobile Phones</td>
</tr>
<tr>
<td>LTC4400</td>
<td>ThinSOT RF PA Controller</td>
<td>Multiband GSM/DCS/GPRS Phones, 45dB Dynamic Range, 450kHz Loop BW</td>
</tr>
<tr>
<td>LTC4401</td>
<td>ThinSOT RF PA Controller</td>
<td>Multiband GSM/DCS/GPRS Phones, 45dB Dynamic Range, 250kHz Loop BW</td>
</tr>
<tr>
<td>LTC4403</td>
<td>Multiband RF Power Controllers for EDGE/TDMA</td>
<td>Supports EDGE/TDMA Applications</td>
</tr>
<tr>
<td>LT5504</td>
<td>800MHz to 2.7GHz RF Measuring Receivers</td>
<td>80dB Dynamic Range, Temperature Compensated, 2.7V to 5.5V Supply</td>
</tr>
<tr>
<td>LT5505</td>
<td>300MHz to 3.5GHz RF Power Detector</td>
<td>&gt;40dB Dynamic Range, Temperature Compensated, 2.7V to 6V Supply</td>
</tr>
<tr>
<td>LT5508</td>
<td>300MHz to 7GHz RF Power Detector</td>
<td>&gt;40dB Dynamic Range, SC-70 Package</td>
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<tr>
<td><strong>Other Related Parts</strong></td>
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<tr>
<td>LT5500</td>
<td>1.8GHz to 2.7GHz, Receiver Front End</td>
<td>Dual LNA gain Setting +13.5dB/-14dB at 2.5GHz, Double-Balanced Mixer, 1.8V to 5.25V Supply</td>
</tr>
<tr>
<td>LT5502</td>
<td>400MHz Quadrature Demodulator with RSSI</td>
<td>1.8V to 5.25V Supply, 70MHz to 400MHz IF, 84dB Limiting Gain, 90dB RSSI Range</td>
</tr>
<tr>
<td>LT5503</td>
<td>1.2GHz to 2.7GHz Direct IQ Modulator and Up Converting Mixer</td>
<td>1.8V to 5.25V Supply, Four-Step RF Power Control, 120MHz Modulation Bandwidth</td>
</tr>
<tr>
<td>LT5506</td>
<td>500MHz Quadrature IF Demodulator with VGA</td>
<td>1.8V to 5.25V Supply, 40MHz to 500MHz IF, –4dB to 57dB Linear Power Gain</td>
</tr>
<tr>
<td>LT5511</td>
<td>High Signal Level Upconverting Mixer</td>
<td>10MHz to 3000MHz RF Output Range, Integrated LO Buffer, 17dBm IIP3</td>
</tr>
<tr>
<td>LT5512</td>
<td>High Signal Level Down Converting Mixer</td>
<td>DC-3GHz, 20dBm IIP3, Integrated LO Buffer</td>
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</table>